NSN 5962-01-293-7702

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View Online at https://aerobasegroup.com/nsn/5962-01-293-7702 **Body Length:** 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and hermetically sealed and asynchronous and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 21 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 150.00 nanoseconds propagation delay time, low to high level output and 150.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Test Data Document:** 81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Shelf Life:

N/a

Unit Of Measure:

28 printed circuit

Specification Data:

Terminal Type And Quantity:

81349-mil-m-38510/292 government specification

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Demilitarization:

Yes - demil/mli

Fiig:

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